

Monolithic CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to V⁻.)

V ⁺	44V
GND.....	25V
Digital Inputs V _S , V _D (Note 1)	-2V to (V ⁺ + 2V) or 20mA, whichever occurs first
Current, Any Terminal Except S or D.....	30mA
Continuous Current, S or D.....	20mA
Peak Current, S or D (pulsed at 1ms, 10% duty cycle max)...	40mA
Continuous Power Dissipation (T _A = +70°C)*	
28-Pin Ceramic DIP (derate 16.7mW/°C above +70°C) ..	1333mW
28-Pin Plastic DIP (derate 14.3mW/°C above +70°C) ..	1143mW

*All leads soldered or welded to PCB.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

28-Pin Wide SO (derate 12.5mW/°C above +70°C) ..	1000mW
28-Pin LCC (derate 10.2mW/°C above +70°C)	816.3mW
Operating Temperature Range (A Suffix)	-55°C to +125°C
(B Suffix)	-25°C to +85°C
(C Suffix)	0°C to +70°C
Storage Temperature (A and B Suffix).....	-65°C to +150°C
(C Suffix)	-65°C to +125°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	
Lead (Pb)-free packages	+260°C
Packages containing lead (Pb).....	+240°C

ELECTRICAL CHARACTERISTICS

(V⁺ = 15V, V⁻ = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise indicated.)

PARAMETER	SYMBOL	CONDITIONS		DG506AA DG507AA			DG506AB/C DG507AB/C			UNITS
				MIN (Note 2)	TYP (Note 3)	MAX	MIN (Note 2)	TYP (Note 3)	MAX	
SWITCH										
Analog Signal Range	VANALOG			-15		+15	-15		+15	V
Drain-to-Source On-Resistance	RDS(ON)	Sequence each switch on, VAL = 0.8V, VAH = 2.4V, VEN = 2.4V	VD = 10V, IS = -200μA	270	400		270	450		Ω
			VD = -10V, IS = -200μA	230	400		230	450		
Greatest Change in Drain-Source On-Resistance Between Channels	RDS(ON)	$\Delta R_{DS(ON)} = \left(\frac{R_{DS(ON)MAX} - R_{DS(ON)MIN}}{R_{DS(ON)AVE}} \right)$ -10V ≤ VS ≤ +10V		6			6			%
Source Off-Leakage Current	IS(OFF)	VEN = 0.8V, VAL = 0.8V	VS = 10V, VD = -10V	-1	0.002	+1	-5	0.002	+5	nA
			VS = -10V, VD = 10V	-1	-0.005	+1	-5	-0.005	+5	
Drain Off-Leakage Current	ID(OFF)	DG506A, VEN = 0.8V, VAL = 0.8V	VD = 10V, VS = -10V	-10	0.02	+10	-20	0.02	+20	nA
			VD = -10V, VS = 10V	-10	-0.03	+10	-20	-0.03	+20	
		DG507A, VEN = 0.8V, VAL = 0.8V	VD = 10V, VS = -10V	-5	0.007	+5	-10	0.007	+10	
			VD = -10V, VS = 10V	-5	-0.015	+5	-10	-0.015	+10	

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ELECTRICAL CHARACTERISTICS (continued)

(V₊ = 15V, V₋ = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise indicated.)

PARAMETER	SYMBOL	CONDITIONS		DG506AA DG507AA			DG506AB/C DG507AB/C			UNITS
				MIN (Note 2)	TYP (Note 3)	MAX	MIN (Note 2)	TYP (Note 3)	MAX	
Channel On-Leakage Current	ID(ON) (Note 4)	DG506A, sequence each switch on, VAL = 0.8V, VAH = 2.4V, VEN = 2.4V	VS(all) = VD = 10V	-10	0.03	+10	-20	0.03	+20	nA
			VS(all) = VD = -10V	-10	-0.06	+10	-20	-0.06	+20	
		DG507A, sequence each switch on, VAL = 0.8V, VAH = 2.4V, VEN = 2.4V	VS(all) = VD = 10V	-5	0.015	+5	-10	0.015	+10	
			VS(all) = VD = -10V	-5	-0.03	+5	-10	-0.03	+10	
INPUT										
Address Input Current, Input- Voltage High	IAH	VA = 2.4V		-10	-0.002		-10	-0.002		μA
		VA = 15V			0.006	10		0.006	10	
Address Input Current, Input- Voltage Low	IAL	All VA = 0V	VEN = 2.4V	-10	-0.002		-10	-0.002		μA
			VEN = 0V	-10	-0.002		-10	-0.002		
DYNAMIC										
Switching Time of Multiplexer	ttransition	Figure 1			0.6	1		0.06		μs
Break-Before- Make Interval	tOPEN	Figure 3			0.2			0.2		μs
Enable Turn- On Time	tON(EN)	Figure 2			1			1		μs
Enable Turn- Off Time	tOFF(EN)	Figure 2			0.4			0.4		μs
Off-Isolation (Note 5)	OIRR	VEN = 0V, RL = 1kΩ, CL = 15pF, VS = 7VRMS, f = 500kHz			68			68		dB
Source Off- Capacitance	CS(OFF)	VEN = 0V, f = 140kHz, VS = 0V			6			6		pF
Drain Off- Capacitance	CD(OFF)	VEN = 0V, f = 140kHz	DG506A, VD = 0V		45			45		pF
			DG507A, VD = 0V		23			23		
SUPPLY										
Positive Supply Current	I+	VEN = 0 or 5V, all VA = 0V			0.13	0.25		0.13	0.3	mA
Negative Supply Current	I-	VEN = 0 or 5V, all VA = 0V		-0.15	-0.07		-0.25	-0.07		

DG506A/DG507A

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ELECTRICAL CHARACTERISTICS (Overtemperature)

(V+ = 15V, V- = -15V, VGND = 0V, TA = otemperature range, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		DG506AA DG507AA			DG506AB/C DG507AB/C			UNITS
				MIN (Note 2)	TYP (Note 3)	MAX	MIN (Note 2)	TYP (Note 3)	MAX	
SWITCH										
Analog Signal Range	V _{ANALOG}			-15		+15	-15		+15	V
Drain-to-Source On-Resistance	R _{DS(ON)}	Sequence each switch on, V _{AL} = 0.8V, V _{AH} = 2.4V, V _{EN} = 2.4V	V _D = 10V, I _S = -200μA			500			550	Ω
			V _D = -10V, I _S = -200μA			500			550	
Source Off-Leakage Current	I _{S(OFF)}	V _{EN} = 0.8V, V _{AL} = 0.8V	V _S = 10V, V _D = -10V	-50		+50	-50		+50	nA
			V _S = -10V, V _D = 10V	-50		+50	-50		+50	
Drain Off-Leakage Current	I _{D(OFF)}	DG506A, V _{EN} = 0.8V, V _{AL} = 0.8V	V _D = 10V, V _S = -10V	-300		+300	-300		+300	nA
			V _D = -10V, V _S = 10V	-300		+300	-300		+300	
		DG507A, V _{EN} = 0.8V, V _{AL} = 0.8V	V _D = 10V, V _S = -10V	-200		+200	-200		+200	
			V _D = -10V, V _S = 10V	-200		+200	-200		+200	
Channel On-Leakage Current	I _{D(ON)} (Note 4)	DG506A, sequence each switch on, V _{AL} = 0.8V, V _{AN} = 2.4V, V _{EN} = 2.4V	V _{S(all)} = V _D = 10V	-300		+300	-300		+300	nA
			V _{S(all)} = V _D = -10V	-300		+300	-300		+300	
		DG507A, sequence each switch on, V _{AL} = 0.8V, V _{AN} = 2.4V, V _{EN} = 2.4V	V _{S(all)} = V _D = 10V	-200		+200	-200		+200	
			V _{S(all)} = V _D = -10V	-200		+200	-200		+200	
INPUT										
Address Input Current, Input-Voltage High	I _{AH}	V _A = 2.4V		-30			-30			μA
		V _A = 15V				30			30	
Address Input Current, Input-Voltage Low	I _{AL}	All V _A = 0V	V _{EN} = 2.4V	-30			-30			μA
			V _{EN} = 0V			30			30	

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ELECTRICAL CHARACTERISTICS (Overtemperature) (continued)

(V+ = 15V, V- = -15V, VGND = 0V, TA = over temperature range, unless otherwise noted.)

Note 1: Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

Note 2: The algebraic convention whereby the most negative value is a minimum, and the most positive value is a maximum, is used in this data sheet.

Note 3: Typical values are for design aid only, not guaranteed nor subject to production testing.

Note 4: ID(ON) is leakage from driver into on switch.

Note 5: Off-isolation = 20log x VO/VS, VS = input to off switch, VD = output due to VS.

Truth Tables

A3	A2	A1	A0	EN	ON SWITCH
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
0	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14
1	1	1	0	1	15
1	1	1	1	1	16

A2	A1	A0	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

Note: Logic "0" = $V_{AL} \leq 0.8V$, Logic "1" = $V_{AH} \geq 2.4V$, "0" = Don't Care.

Switching Time Test Circuits

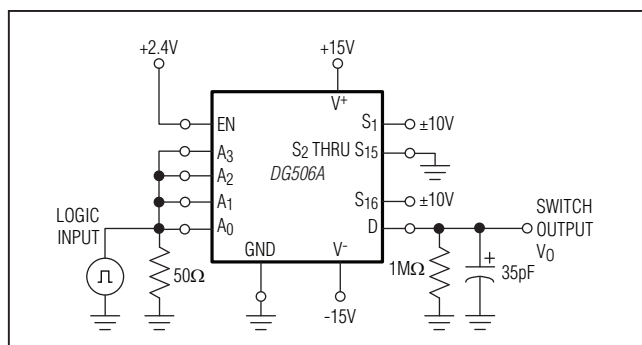


Figure 1a. Transition Switching Time

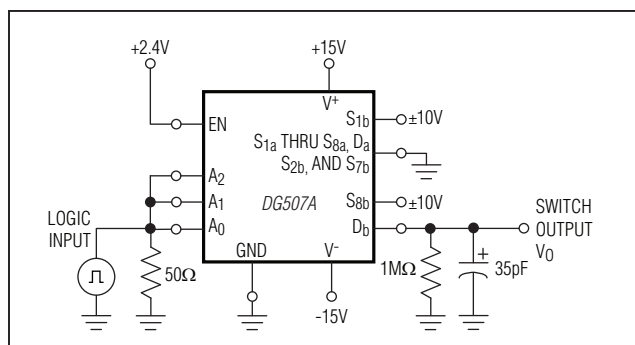


Figure 1b. Transition Switching Time

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Switching Time Test Circuits (continued)

DG506A/DG507A

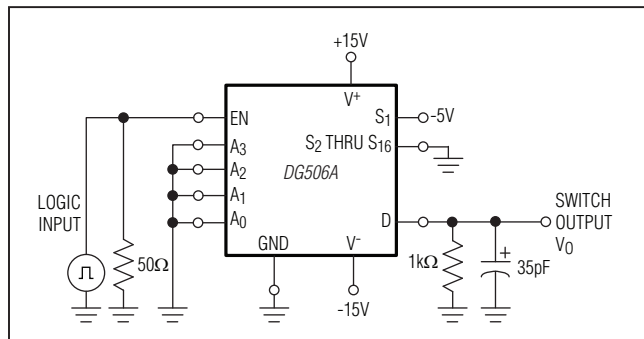


Figure 2a. Enable Switching Time

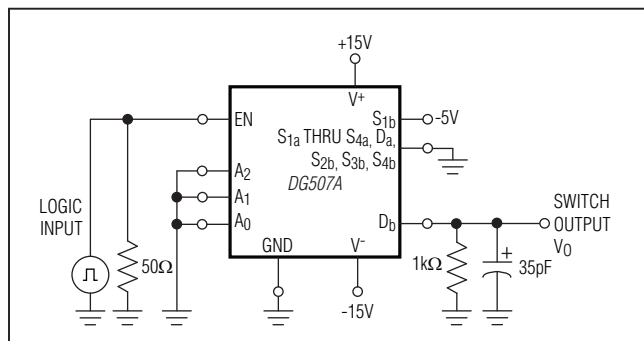


Figure 2b. Enable Switching Time

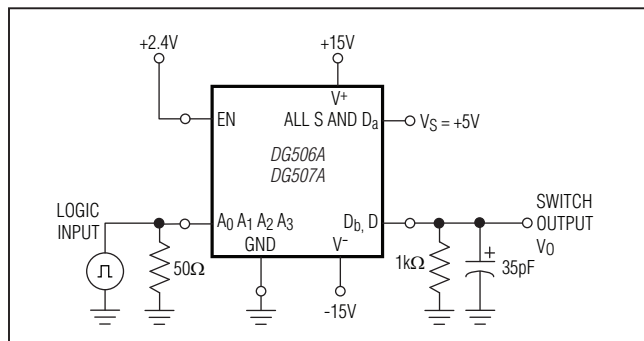


Figure 3. Break-Before-Make

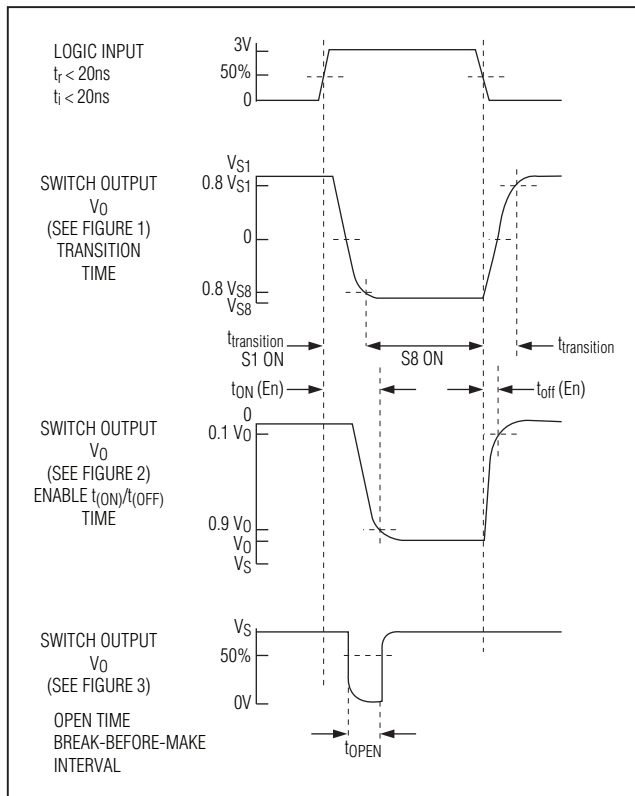
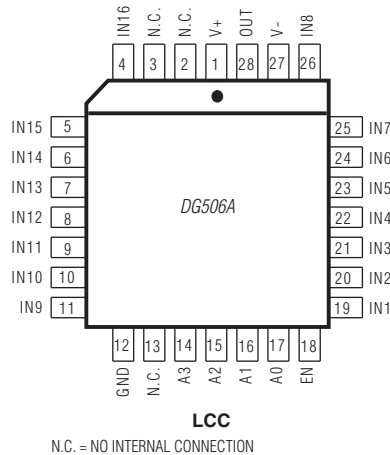


Figure 4. Timing Diagrams for Figures 1, 2, and 3

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Pin Configurations (continued)

DG506A/DG507A



Pin Description

PIN		NAME	FUNCTION
DG506A DIP / SO	DG507A DIP / SO		
1	1	V+	Positive Supply Voltage Input
2, 3	3	N.C.	No Connection. Internally not connected.
—	2	D _b	Analog Output Bidirectional Channel b
4	—	S ₁₆	Analog Output Bidirectional Channel 16
—	4	S _{8b}	Analog Output Bidirectional Channel 8b
5	—	S ₁₅	Analog Output Bidirectional Channel 15
—	5	S _{7b}	Analog Output Bidirectional Channel 7b
6	—	S ₁₄	Analog Output Bidirectional Channel 14
—	6	S _{6b}	Analog Output Bidirectional Channel 6b
7	—	S ₁₃	Analog Output Bidirectional Channel 13
—	7	S _{5b}	Analog Output Bidirectional Channel 5b
8	—	S ₁₂	Analog Output Bidirectional Channel 12
—	8	S _{4b}	Analog Output Bidirectional Channel 4b
9	—	S ₁₁	Analog Output Bidirectional Channel 11
—	9	S _{3b}	Analog Output Bidirectional Channel 3b
10	—	S ₁₀	Analog Output Bidirectional Channel 10
—	10	S _{2b}	Analog Output Bidirectional Channel 2b
11	—	S ₉	Analog Output Bidirectional Channel 9
—	11	S _{1b}	Analog Output Bidirectional Channel 1b
12	12	GND	Ground

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Pin Description (continued)

PIN		NAME	FUNCTION
DG506A DIP / SO	DG507A DIP / SO		
13	13, 14	N.C.	No Connection. Not internally connected.
14	—	A3	Address Input A3
15	15	A2	Address Input A2
16	16	A1	Address Input A1
17	17	A0	Address Input A0
18	18	EN	Enable Input
19	—	S ₁	Analog Output Bidirectional Channel 1
—	19	S _{1A}	Analog Output Bidirectional Channel 1a
20	—	S ₂	Analog Output Bidirectional Channel 2
—	20	S _{2A}	Analog Output Bidirectional Channel 2a
21	—	S ₃	Analog Output Bidirectional Channel 3
—	21	S _{3A}	Analog Output Bidirectional Channel 3a
22	—	S ₄	Analog Output Bidirectional Channel 4
—	22	S _{4A}	Analog Output Bidirectional Channel 5
23	—	S ₅	Analog Output Bidirectional Channel 5a
—	23	S _{5a}	Analog Output Bidirectional Channel 6
24	—	S ₆	Analog Output Bidirectional Channel 6a
—	24	S _{6a}	Analog Output Bidirectional Channel 7
25	—	S ₇	Analog Output Bidirectional Channel 7a
—	25	S _{7a}	Analog Output Bidirectional Channel 8
26	—	S ₈	Analog Output Bidirectional Channel 8a
—	26	S _{8a}	Analog Output Bidirectional Channel
27	27	V-	Negative Supply Voltage Input
28	—	D	Analog Output Bidirectional
—	28	Da	Analog Output Bidirectional Channel a

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Pin Description (continued)

DG506A/DG507A

PIN	NAME	FUNCTION
DG506A LCC		
1	V+	Positive Supply Voltage Input
2, 3	N.C.	NoConnection. Internally not connected.
4	IN ₁₆	Analog Input Bidirectional Channel 16
5	IN ₁₅	Analog Input Bidirectional Channel 15
6	IN ₁₄	Analog Input Bidirectional Channel 14
7	IN ₁₃	Analog Input Bidirectional Channel 13
8	IN ₁₂	Analog Input Bidirectional Channel 12
9	IN ₁₁	Analog Input Bidirectional Channel 11
10	IN ₁₀	Analog Input Bidirectional Channel 10
11	IN ₉	Analog Input Bidirectional Channel 9
12	GND	Ground
13	N.C.	No Connection. Not internally connected.
14	A3	Address Input A3
15	A2	Address Input A2
16	A1	Address Input A1
17	A0	Address Input A0
18	EN	Enable Input
19	IN ₁	Analog Input Bidirectional Channel 1
20	IN ₂	Analog Input Bidirectional Channel 2
21	IN ₃	Analog Input Bidirectional Channel 3
22	IN ₄	Analog Input Bidirectional Channel 4
23	IN ₅	Analog Input Bidirectional Channel 5
24	IN ₆	Analog Input Bidirectional Channel 6
25	IN ₇	Analog Input Bidirectional Channel 7
26	IN ₈	Analog Input Bidirectional Channel 8
27	V-	Negative Supply Voltage Input
28	OUT	Analog Output Bidirectional

Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix number, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
28 CERDIP	J28-2	21-0046	—
28 Plastic DIP	P28-2	21-0044	—
28 Wide SO	W28-5	21-0042	90-0109
28 Wide SO	W28-5	21-0047	90-0178
28 LCC	L28-2	21-4497	90-0178

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	8/92	Initial release	—
1	1/99	Updated to Word format.	1–7
2	5/09	Added ruggedized plastic part.	1–4, 7
3	2/10	- Added lead temperature to the <i>Absolute Maximum Ratings</i>. - Changed the derate rate of all packages to above 70°C in the <i>Absolute Maximum Ratings</i>.	2
4	6/12	Added DG506AAZ/883B; added the Pin Descriptions for DG506A DIP/SO, DG507A DIP/SO, DG506A LCC; added LCC Pin Configuration for the DG506A	1, 2, 7, 9

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